VS-E4PH3006LHN3

Vishay Semiconductors



Hyperfast Soft Recovery Diode, 30 A FRED Pt® Gen 4



PRODUCT SUMMARY								
I _{F(AV)}	30 A							
V _R	600 V							
V _F at I _F	1.37 V							
t _{rr} typ.	see Recovery table							
T _J max.	175 °C							
Package	TO-247AD 2L							
Diode variation	Single die							

FEATURES

- Gen 4 FRED Pt[®] technology
- Low I_{BBM} and reverse recovery charge
- · Very low forward voltage drop
- · Polymide passivated chip for high reliability standard
- 175 °C operating junction temperature
- AEC-Q101 gualified, meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

Gen 4 Fred technology, state of the art, ultrafast V_F, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS					
Cathode to anode voltage	V _R		600	V					
Average rectified current	I _{F(AV)}	T _C = 122 °C	30						
Single pulse forward current	I _{FSM}	T_C = 25 °C, t_p = 8.3 ms half sine wave	240	A					
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C					

ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	600	-	-				
		I _F = 30 A	-	1.65	2				
		I _F = 60 A	-	1.95	-				
Forward voltage	V	I _F = 30 A, T _J = 125 °C	-	1.44	-	V			
Forward Voltage	V _F	I _F = 60 A, T _J = 125 °C	-	1.78	-				
		I _F = 30 A, T _J = 150 °C	-	1.37	1.6	1			
		I _F = 60 A, T _J = 150 °C	-	1.68	-				
		V _R = V _R rated	-	-	50				
Reverse leakage current	I _R	$T_J = 150 \ ^\circ C, V_R = V_R \text{ rated}$	-	-	500	μΑ			
Junction capacitance	CT	V _R = 600 V	-	18.3	-	pF			





HALOGEN

FREE

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST C	TEST CONDITIONS			MAX.	UNITS		
Reverse recovery time	+	T _J = 25 °C		-	55	-	ns		
	t _{rr}	T _J = 125 °C	I _F = 30 A dI _F /dt = 1000 A/μs V _B = 400 V	-	75	-			
Peak recovery current	I _{RRM}	T _J = 25 °C		-	13	-	A		
		T _J = 125 °C		-	23	-			
Reverse recovery charge	Q _{rr}	T _J = 25 °C	vR = 400 v	-	500	-	nC		
		T _J = 125 °C		-	1250	-			

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Thermal resistance, junction to case	R _{thJC}		-	-	1	°C/W			
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.4	-				
Weight			-	6.0	-	g			
Weight			-	0.21	-	oz.			
Mounting torque			6.0	_	12	kgf · cm			
			(5)	-	(20)	$(lbf \cdot in)$			
Marking device		Case style TO-247AD 2L		E4PH3	3006LH	-			

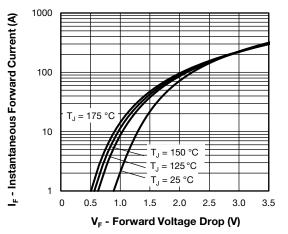
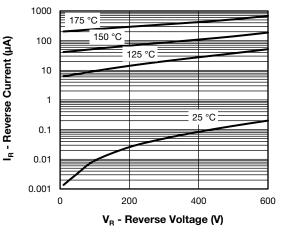
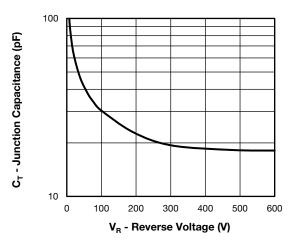


Fig. 1 - Typical Forward Voltage Drop Characteristics









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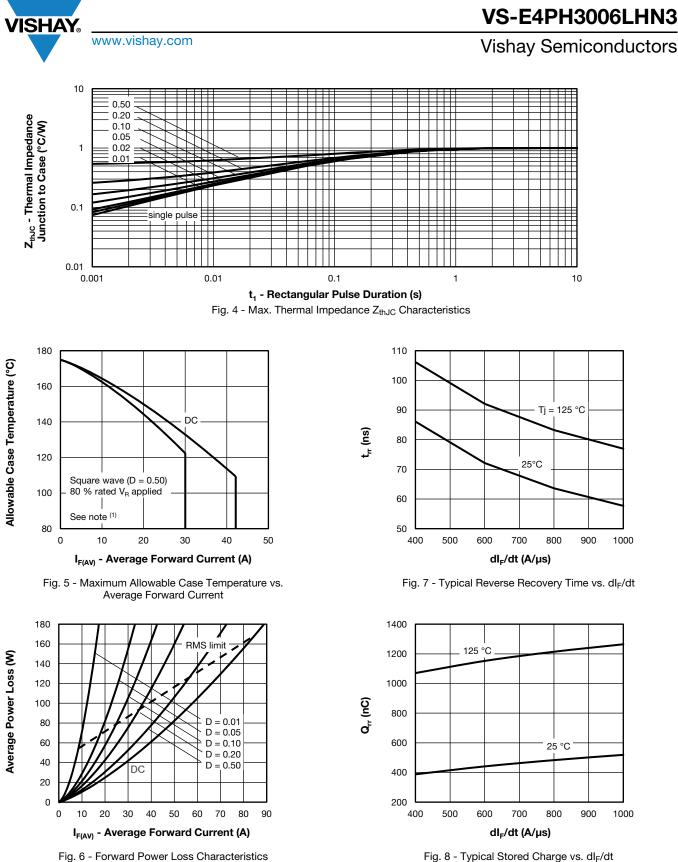


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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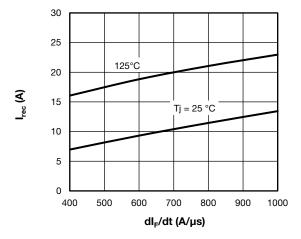


Fig. 9 - Typical Reverse Current vs. dl_F/dt

ORDERING INFORMATION TABLE

Device code	VS-	Е	4	Р	Н	30	06	L	Н	N3		
	1	2	3	4	5	6	7	8	9	10		
	1 - 2 -											
	3 -	FRE	ED Pt G		-							
	4 · 5 ·	Pro	cess typ									
	6 · 7 ·											
	8 -	- L = long lead										
		 9 - H = AEC-Q101 qualified 10 - Environmental digit: N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free 										

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-E4PH3006LHN3	25	500	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS								
Dimensions TO-247AD 2L www.vishay.com/doc?95536								
Part marking information	TO-247AD 2L	www.vishay.com/doc?95648						

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TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

View	<u>/ B</u>

SYMBOL	MILLIN	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX. MIN. MAX.		STMDUL	MIN.	MAX.	MIN.	MAX.	NOTES			
А	4.65	5.31	0.183	0.209			E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102			E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098			е	5.46	BSC	0.215	5 BSC	
b	0.99	1.40	0.039	0.055			ØК	0.2	254	0.0	010	
b1	0.99	1.35	0.039	0.053			L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51 BSC 0.217		' BSC		
D2	0.51	1.35	0.020	0.053				•		•		•

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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